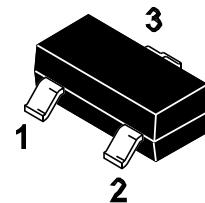




## Features

- Surface mount package
- Halogen free product is acquired
- High power and current handing capability
- $V_{DS} = -20V, I_D = -2.8A$
- $R_{DS(on)} < 110m\Omega @ V_{GS} = -4.5V$

SOT-23



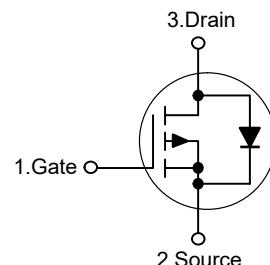
1. Gate 2. Source 3. Drain

Marking Code:M01

## Applications

- Battery protection
- Load switch
- Power management

Schematic Diagram



## Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$-V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current-Continuous	$-I_D$	2.8	A
Drain Current-Pulsed <sup>Note1</sup>	$-I_{DM}$	10	A
Maximum Power Dissipation	$P_D$	0.7	W
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

## Thermal Characteristics

Thermal Resistance, Junction-to-Ambient <sup>Note2</sup>	$R_{θJA}$	179	°C/W
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## Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	-V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	20	--	--	V
Zero Gate Voltage Drain Current	-I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	--	--	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V	--	--	±100	nA
Gate Threshold Voltage <sup>Note3</sup>	-V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	0.4	0.7	1	V
Drain-Source On-Resistance <sup>Note3</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.8A	--	78	110	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2A	--	102	140	mΩ
Forward Transconductance <sup>Note3</sup>	g <sub>FS</sub>	V <sub>DS</sub> =-5V, I <sub>D</sub> =-2.8A	--	2	--	S
<b>Dynamic Characteristics</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1MHz	--	325	--	pF
Output Capacitance	C <sub>oss</sub>		--	63	--	pF
Reverse Transfer Capacitance	C <sub>rss</sub>		--	37	--	pF
<b>Switching Characteristics</b>						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =-10V, R <sub>L</sub> =5Ω, V <sub>GS</sub> =-4.5V, R <sub>GEN</sub> =3Ω	--	11	--	nS
Turn-on Rise Time	t <sub>r</sub>		--	5.5	--	nS
Turn-off Delay Time	t <sub>d(off)</sub>		--	22	--	nS
Turn-off Fall Time	t <sub>f</sub>		--	8	--	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-2A, V <sub>GS</sub> =-4.5V	--	3.2	--	nC
Gate-Source Charge	Q <sub>gs</sub>		--	0.6	--	nC
Gate-Drain Charge	Q <sub>gd</sub>		--	0.9	--	nC
<b>Source-Drain Diode Characteristics</b>						
Diode Forward Voltage <sup>Note3</sup>	-V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-2.8A	--	--	1.2	V
Diode Forward Current <sup>Note2</sup>	-I <sub>S</sub>		--	--	2.8	A

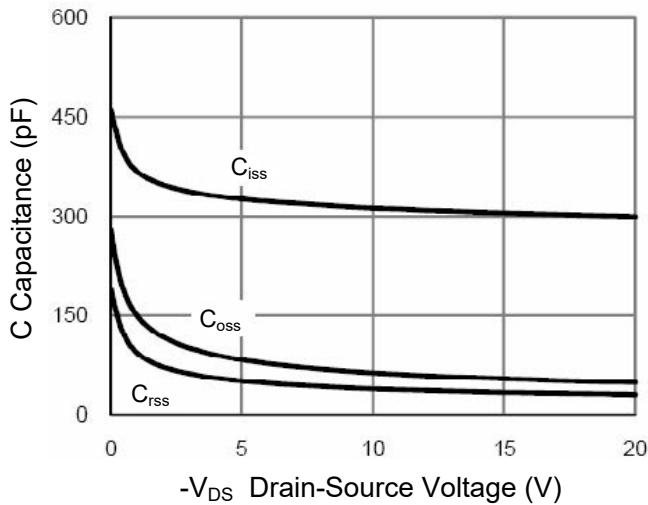
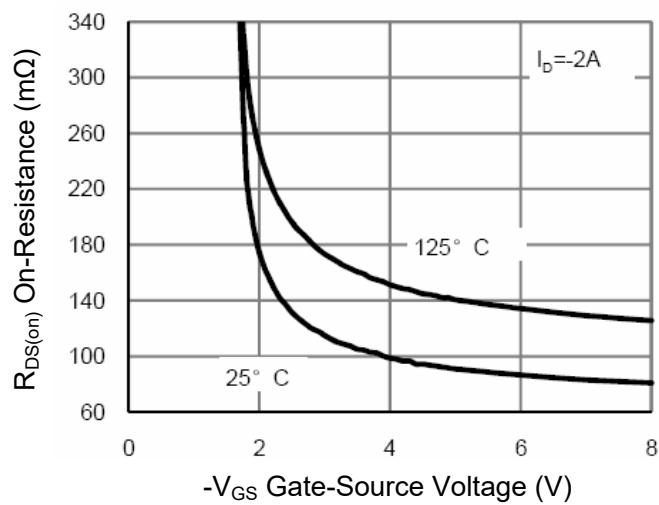
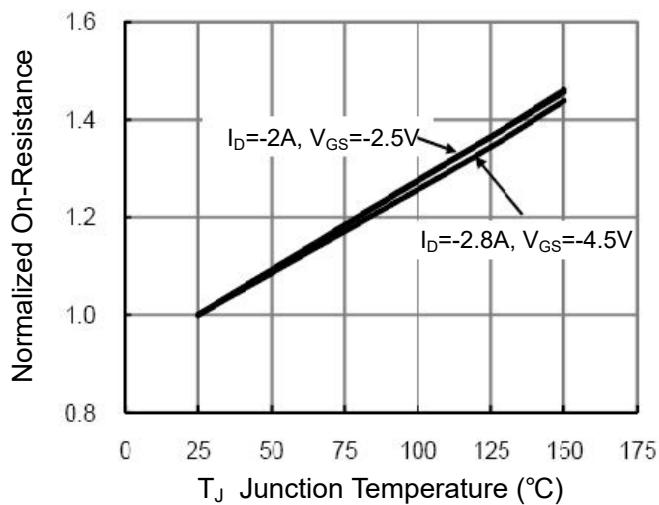
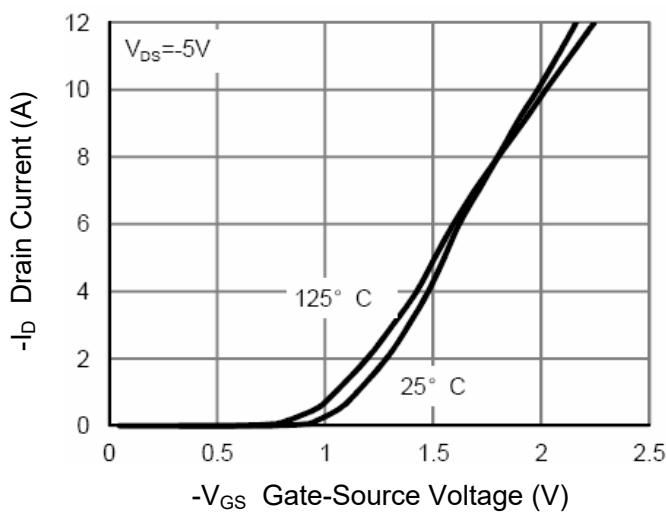
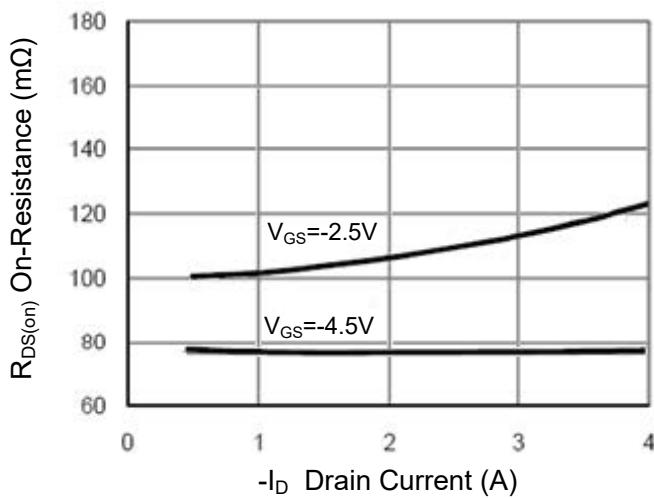
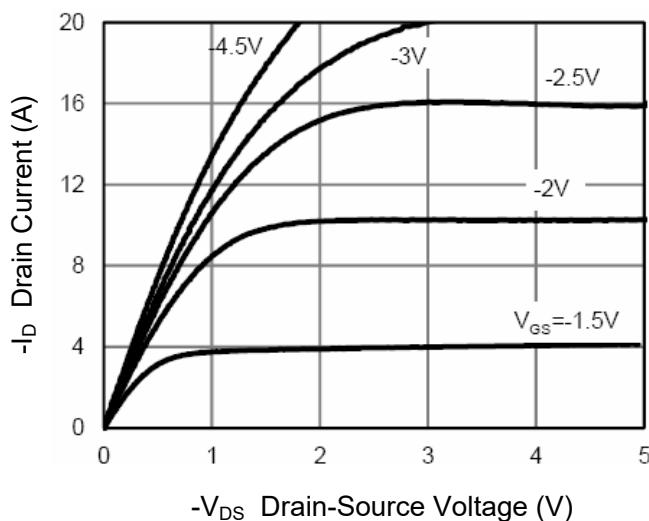
Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

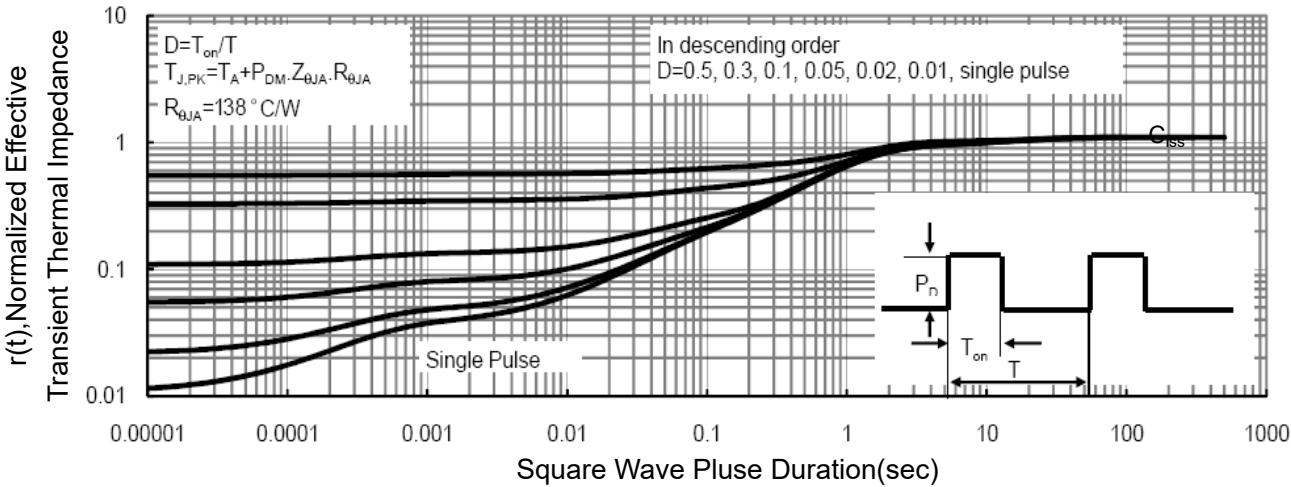
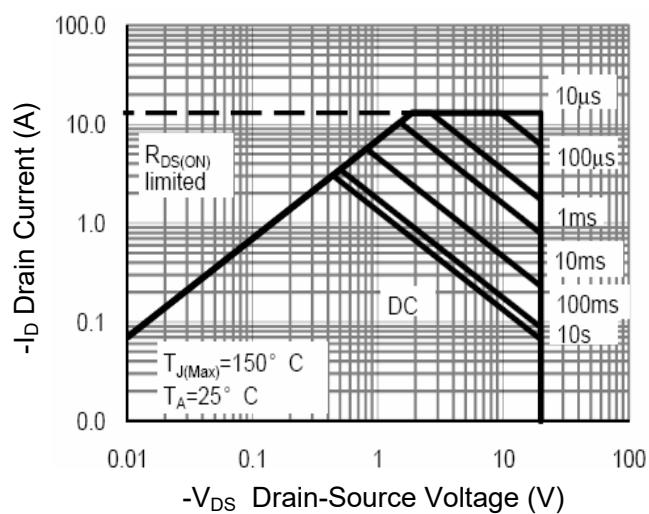
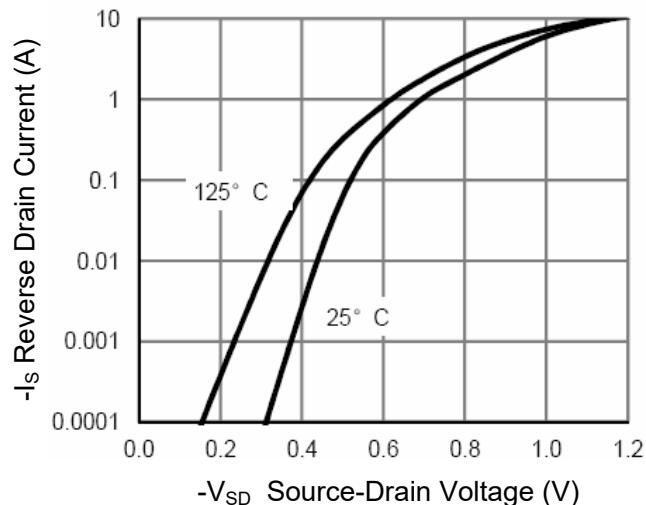
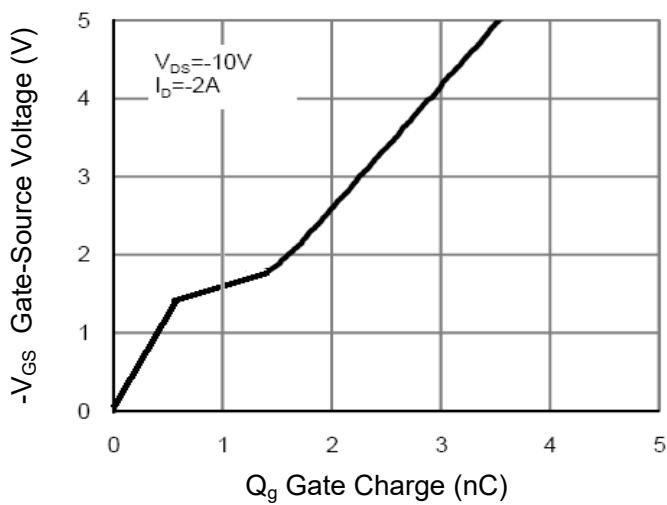
2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.



## Typical Characteristic Curves



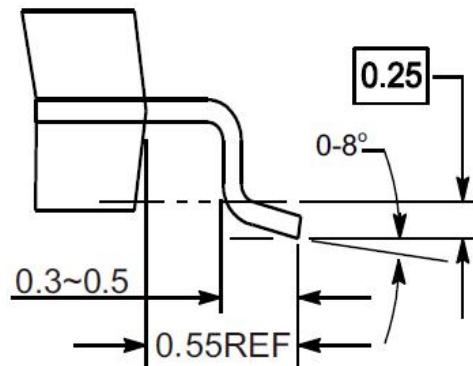
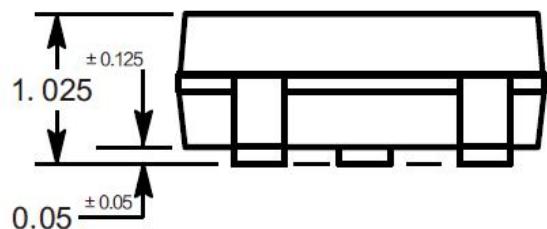
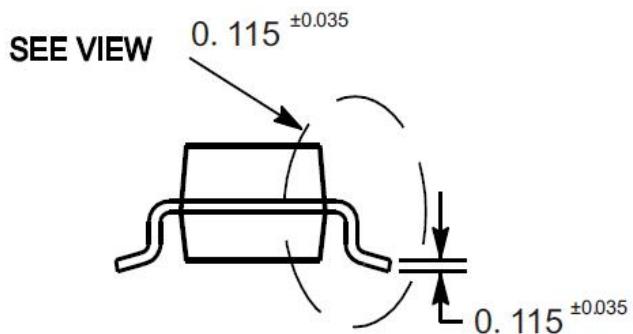
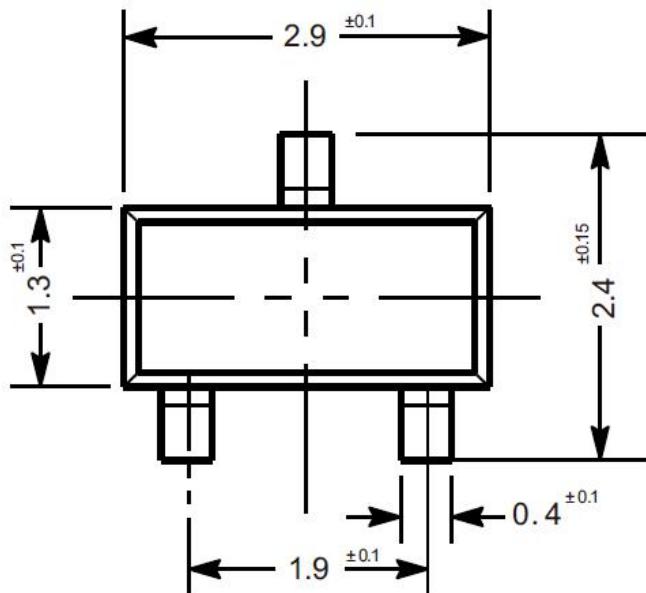




## Package Outline

SOT-23

Dimensions in mm



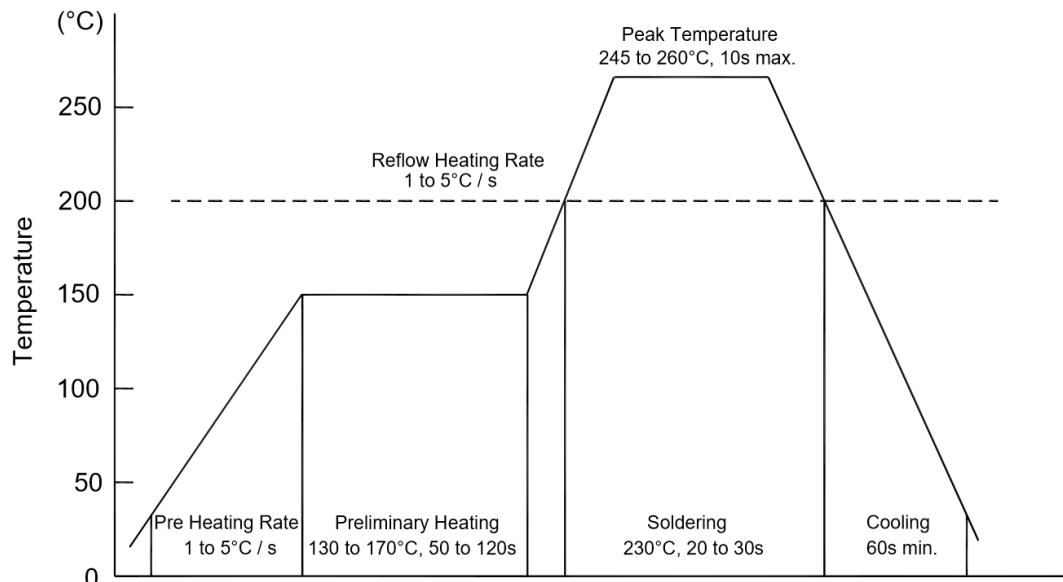
## Ordering Information

Device	Package	Shipping
SI2301	SOT-23	3,000PCS/Reel&7inches



## Conditions of Soldering and Storage

### ◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### ◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

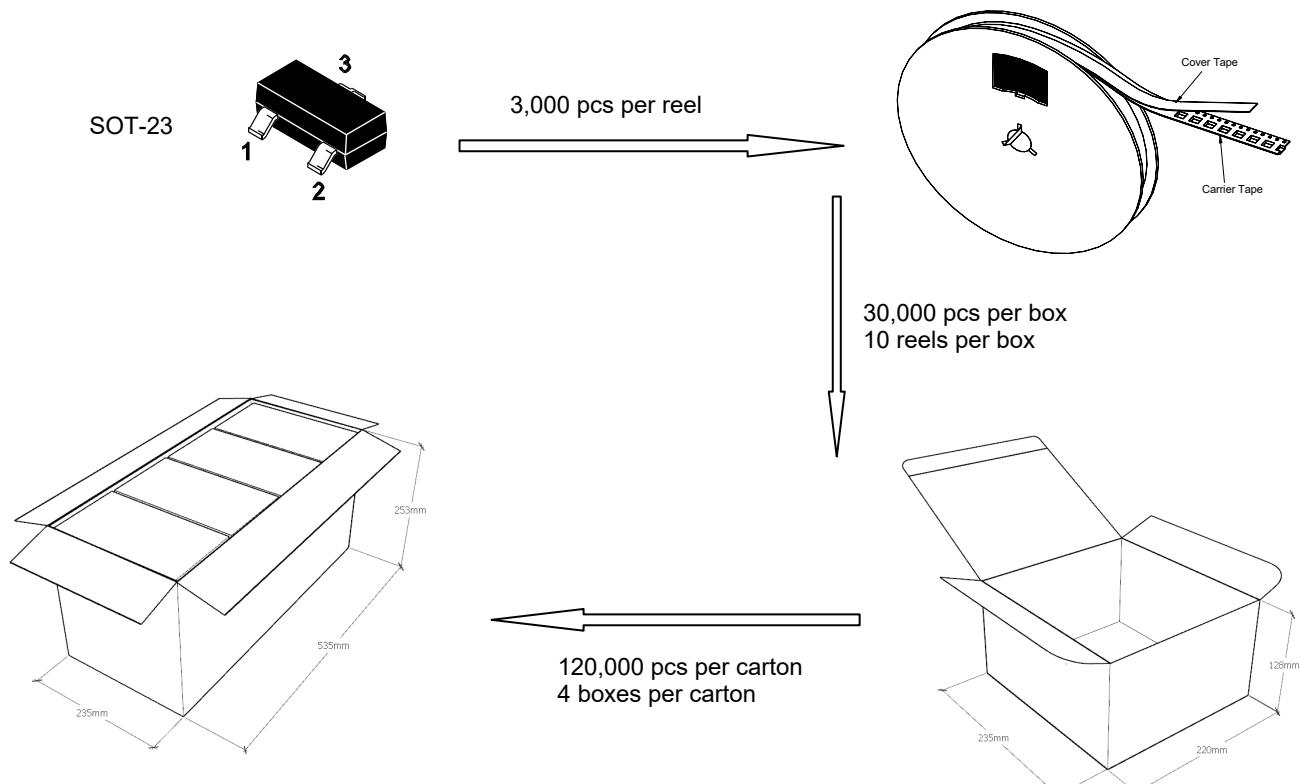
### ◆ Storage conditions

- **Temperature**  
5 to 40 °C
- **Humidity**  
30 to 80% RH
- **Recommended period**  
One year after manufacturing

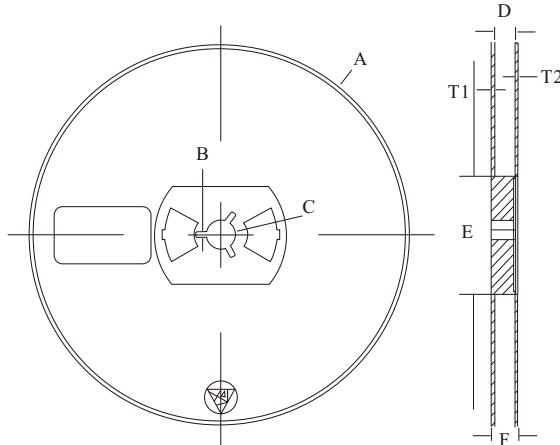


## Package Specifications

- The method of packaging

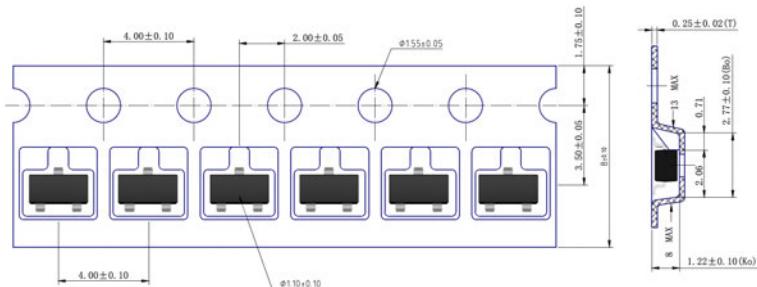


### ◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	Ø 177.8±1.0
B	2.7±0.2
C	Ø 13.5±0.2
E	Ø 54.5±0.2
F	12.3±0.3
D	9.6+2/-0.3
T1	1.0±0.2
T2	1.2±0.2

Reel (7")



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[IPS60R360PFD7SAKMA1](#) [IPS60R600PFD7SAKMA1](#)